High Performance Driver/Comparator, Active Load on a Single Chip

AD53509

FEATURES

250 MHz operation
Driver/comparator and active load included
On-chip Schottky diode bridge
52-lead LQFP_EP package

APPLICATIONS

Automatic test equipment (ATE)
Semiconductor test systems
Board test systems
Instrumentation and characterization equipment

GENERAL DESCRIPTION

The AD53509 is a single chip that performs the pin electronics functions of driver, comparator, and active load in ATE VLSI and memory testers. In addition, a Schottky diode bridge for the active load and a VCOM buffer are included internally.

The driver is a proprietary design that features three active states: data high mode, data low mode, and term mode as well as an inhibit state. The output voltage range is −2 V to +7 V to accommodate a wide variety of test devices. The output leakage is typically <250 nA over the signal range.

The dual comparator, with an input range equal to the driver output range, features built-in latches and ECL-compatible outputs. The outputs are capable of driving 50 Ω signal lines terminated to −2 V. Signal tracking capability is >5 V/ns.

The active load can be set up to 40 mA load current with less than a 10 μA linearity error through the set range. I_{OH}, I_{OL}, and the buffered VCOM are independently adjustable. On-board Schottky diodes provide high speed switching and low capacitance.

Also included on the chip is an on-board temperature sensor whose purpose is to give an indication of the surface temperature of the DCL. This information can be used to measure θ_{JC} and θ_{JA} or flag an alarm if proper cooling is lost. Output from the sensor is a current sink that is proportional to absolute temperature. The gain is trimmed to a nominal value of 1.0 μA/K. For example, the output current can be sensed by using a 10 kΩ resistor connected from 10 V to the THERM pin. A voltage drop across the resistor then develops that equals

$$10 \text{ K} \times 1 \text{ μA/K} = 10 \text{ mV/K} = 2.98 \text{ V (at room temperature)}$$
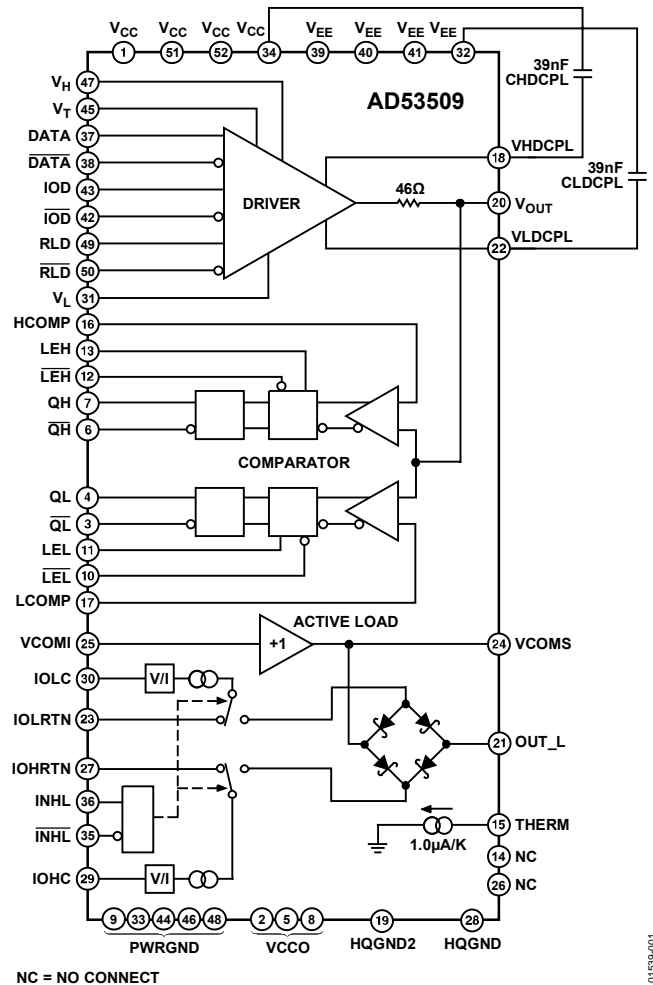
FUNCTIONAL BLOCK DIAGRAM

NC = NO CONNECT

Figure 1.

One Technology Way, P.O. Box 9106, Norwood, MA 02062-9106, U.S.A.
Tel: 781.329.4700   **www.analog.com**
Fax: 781.461.3113

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DRIVER SPECIFICATIONS

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Table 1.

Parameter	Min	Typ	Max	Unit	Test Conditions
DIFFERENTIAL INPUT CHARACTERISTICS, DATA to DATA, IOD to IOD, RLD to RLD					
Input Voltage	−2		+3	V	
Differential Input Range			2	V	All digital inputs within a 2 V range
Bias Current	−250		+250	µA	$V_{IN} = −2\ V, +3\ V$
REFERENCE INPUTS					
Bias Currents	−50		+50	µA	$V_L, V_H, V_T = 5\ V$
OUTPUT CHARACTERISTICS					
Logic High Range	−2		+7	V	Data = H, $V_H = −2\ V$ to $+7\ V$, $V_L = −2\ V$, $V_T = 0\ V$
Logic Low Range	−2		+6	V	Data = L, $V_L = −2\ V$ to $+6\ V$, $V_H = 7\ V$, $V_T = 0\ V$
Amplitude, V_H and V_L	0.1		9	V	$V_L = 0\ V, V_H = 0.1\ V, V_T = 0\ V$
Absolute Accuracy					$V_L = −2\ V, V_H = 7\ V, V_T = 0\ V$
V_H Offset	−50		+50	mV	Data = H, $V_H = 0\ V, V_L = −2\ V, V_T = −1\ V$
V_H Gain + Linearity Error	0.3 − 5		0.3 + 5	% of V_H + mV	Data = H, $V_H = −1\ V$ to $+7\ V$, $V_L = −2\ V, V_T = −2\ V$
V_L Offset	−50		+50	mV	Data = L, $V_L = 0\ V, V_H = 5\ V, V_T = 3\ V$
V_L Gain + Linearity Error	−0.3 − 5		+0.3 + 5	% of V_L + mV	Data = L, $V_L = −2\ V$ to $+6\ V$, $V_H = 7\ V, V_T = 7\ V$
Offset Temperature Coefficient		0.5		mV/°C	$V_L = −2\ V, V_H = 0\ V, V_T = −1\ V$ (V_H offset), $V_L = 0\ V, V_H = 5\ V, V_T = 3\ V$ (V_L offset)
Output Resistance					
$V_H = −2\ V$	44	46	48	Ω	$V_L = −2\ V, V_T = 0\ V, I_{OUT} = 0\ mA, 1\ mA, 30\ mA$
$V_H = +7\ V$	44	46	48	Ω	$V_L = −1\ V, V_T = 0\ V, I_{OUT} = 0\ mA, −1\ mA, −30\ mA$
$V_L = −2\ V$	44	46	48	Ω	$V_H = 6\ V, V_T = 0\ V, I_{OUT} = 0\ mA, 1, mA\ 30\ mA$
$V_L = +6\ V$	44	46	48	Ω	$V_H = 7\ V, V_T = 0\ V, I_{OUT} = 0\ mA, −1\ mA, −30\ mA$
$V_H = +3\ V$		46		Ω	$V_L = 0\ V, V_T = 0\ V, I_{OUT} = −30\ mA$ (trim point)
Dynamic Current Limit		>100		mA	$C_{BYP} = 39\ nF, V_H = 6\ V, V_L = −2\ V, V_T = 0\ V$
Static Current Limit	−85		+85	mA	Output to −2 V, $V_H = 7\ V, V_L = −1\ V, V_T = 0\ V$, data = H and output to 7 V, $V_H = 6\ V$, $V_L = −2\ V, V_T = 0\ V$, data = L
V_T					
Voltage Range	−2		+7	V	Term mode, $V_T = −2\ V$ to $+7\ V$, $V_L = 0\ V, V_H = 3\ V$
V_T Offset	−50		+50	mV	Term mode, $V_T = 0\ V, V_L = 0\ V, V_H = 3\ V$
V_T Gain + Linearity Error	−0.3 + 10		+0.3 + 10	% of V_{SET} + mV	Term mode, $V_T = −2\ V$ to $+7\ V$, $V_L = 0\ V, V_H = 3\ V$
Offset Temperature Coefficient		0.5		mV/°C	$V_T = 0\ V, V_L = 0\ V, V_H = 3\ V$
Output Resistance	44	46	49	Ω	$I_{OUT} = 30\ mA, 1.0\ mA, V_T = −2.0\ V, V_H = 3\ V$, $V_L = 0\ V, I_{OUT} = −30\ mA, −1.0\ mA, V_T = 7.0\ V$, $V_H = 3\ V, V_L = 0\ V, I_{OUT} = ±30\ mA, ±1.0\ mA$, $V_T = 0\ V, V_H = 3\ V, V_L = 0\ V$
DYNAMIC PERFORMANCE, V_H AND V_L					
Propagation Delay Time		1.5		ns	Measured at 50%, $V_H = 400\ mV$, $V_L = −400\ mV, V_T = 0\ V$
Propagation Delay Temperature Coefficient		2		ps/°C	Measured at 50%, $V_H = 400\ mV$, $V_L = −400\ mV, V_T = 0\ V$
Delay Matching, Edge to Edge		<100		ps	Measured at 50%, $V_H = 400\ mV$, $V_L = −400\ mV, V_T = 0\ V$

Parameter	Min	Typ	Max	Unit	Test Conditions
Rise and Fall Times					
1 V Swing		0.42		ns	Measured 20% to 80%, $V_L = 0$ V, $V_H = 1$ V, $V_T = 0$ V
3 V Swing		0.75		ns	Measured 20% to 80%, $V_L = 0$ V, $V_H = 3$ V, $V_T = 0$ V
5 V Swing		1.65		ns	Measured 10% to 90%, $V_L = 0$ V, $V_H = 5$ V, $V_T = 0$ V
9 V Swing		3.0		ns	Measured 10% to 90%, $V_L = -2$ V, $V_H = 7$ V, $V_T = 0$ V
Rise/Fall Time Temperature Coefficient					
1 V Swing		±1		ps/°C	Measured 20% to 80%, $V_L = 0$ V, $V_H = 1$ V
3 V Swing		±2		ps/°C	Measured 20% to 80%, $V_L = 0$ V, $V_H = 3$ V
5 V Swing		±4		ps/°C	Measured 10% to 90%, $V_L = 0$ V, $V_H = 5$ V
Overshoot and Preshoot		<3 + 50		% of Step + mV	V_L, $V_H = -0.1$ V, +0.1 V, V_L, $V_H = 0$ V, +1.0 V
					V_L, $V_H = 0$ V, 3.0 V, V_L, $V_H = 0$ V, 5.0 V
					V_L, $V_H = -2.0$ V, +7.0 V
Settling Time					
to 15 mV		<50		ns	$V_L = 0$ V, $V_H = 0.5$ V, $V_T = -2$ V
to 4 mV		<10		µs	$V_L = 0$ V, $V_H = 0.5$ V, $V_T = -2$ V
Delay Change vs. Pulse Width		50		ps	$V_L = 0$ V, $V_H = 2$ V, pulse width = 2.5 ns/7.5 ns, 30 ns/90 ns
Minimum Pulse Width					
3 V Swing		1.4		ns	$V_L = 0$ V, $V_H = 3$ V, 90% (2.7 V) reached, measure @ 50%
5 V Swing		2.0		ns	$V_L = 0$ V, $V_H = 5$ V, 90% (4.5 V) reached, measure @ 50%
Toggle Rate		250		MHz	$V_L = 0$ V, $V_H = 5$ V, VDUT > 3.0 V p-p
DYNAMIC PERFORMANCE, INHIBIT					
Delay Time, Active to Inhibit		3.3		ns	Measured at 50%, $V_H = 2$ V, $V_L = -2$ V, $V_T = 0$ V
Delay Time, Inhibit to Active		2.9		ns	Measured at 50%, $V_H = 2$ V, $V_L = -2$ V, $V_T = 0$ V
Delay Time Matching, Z		<2		ns	Z = delay time, active to inhibit − delay time, inhibit to active (of worst two edges)
Input/Output Spike		150		mV p-p	$V_H = 0$ V, $V_L = 0$ V, $V_T = 0$ V
Rise/Fall Time, Active to Inhibit		1.6		ns	$V_H = 2$ V, $V_L = -2$ V (measured 20%/80% of 1 V output)
Rise/Fall Time, Inhibit to Active		1.4		ns	$V_H = 2$ V, $V_L = -2$ V (measured 20%/80% of 1 V output)
DYNAMIC PERFORMANCE, V_T					
Delay Time, V_H to V_T and V_L to V_T		2.5		ns	Measured at 50%, $V_L = -1$ V, $V_H = 1$ V, $V_T = 0$ V
Delay Time, V_T to V_H and V_T to V_L		2.5		ns	Measured at 50%, $V_L = V_H = 0.4$ V, $V_T = -0.4$ V
Overshoot and Preshoot		<3.0 + 75		% of Step + mV	V_H/V_L, $V_T = (0$ V, -1 V), (0 V, -2.0 V), (0 V, +6.0 V)
V_T Mode Rise Time		2.2		ns	$V_L = -2$ V, $V_H = 2$ V, $V_T = 0$ V, 20% to 80%
V_T Mode Fall Time		2.2		ns	$V_L = -2$ V, $V_H = 2$ V, $V_T = 0$ V, 20% to 80%
PSRR, Drive, or Term Mode		35		dB	$V_S = V_S \pm 3\%$

COMPARATOR SPECIFICATIONS

All specifications are at $T_J = 85°C \pm 5°C$. Outputs terminated in 150 Ω to GND, $V_{CC} = 11$ V ± 3%, $V_{EE} = 6$ V ± 3%, VCCO = 3.3 V, unless otherwise specified. All temperatures coefficients are measured at $T_J = 75°C$ to 95°C.

Table 2.

Parameter	Min	Typ	Max	Unit	Test Conditions
DC INPUT CHARACTERISTICS					
Offset Voltage, V_{OS}	−25		+25	mV	CMV = 0 V
Offset Voltage, Drift		50		μV/°C	CMV = 0 V
HCOMP, LCOMP Bias Current	−50		+50	μA	$V_{IN} = 0$ V
Voltage Range, V_{CM}	−2		+7.0	V	
Differential Voltage, V_{DIFF}			9.0	V	
Gain and Linearity	−0.05		+0.05	% FSR	$V_{IN} = -2$ V to +7 V (9 V FSR)
LATCH ENABLE INPUTS					
Logic 1 Current, I_{IH}			250	μA	LEA, $\overline{LEA}$, LEB, $\overline{LEB}$ = 3 V
Logic 0 Current, I_{IL}	−250			μA	LEA, $\overline{LEA}$, LEB, $\overline{LEB}$ = −2 V
Logic Input Range	−2		+3	V	
DIGITAL OUTPUTS					
Logic 1 Voltage, V_{OH}	VCCO − 0.98			V	Qx or $\overline{Qx}$, 16.7 mA load
Logic 0 Voltage, V_{OL}			VCCO − 1.5	V	Qx or $\overline{Qx}$, 10 mA load
Slew Rate		1		V/ns	
VCCO Range	0		8	V	
SWITCHING PERFORMANCE					
Propagation Delay					
Input to Output		1.8		ns	$V_{IN} = 2$ V p-p
Latch Enable to Output		2		ns	HCOMP = 1 V, LCOMP = 1 V
Propagation Delay Temperature Coefficient		2		ps/°C	
Propagation Delay Change with Respect to					
Slew Rate: 0.5 V/ns, 1.0 V/ns, 3.0 V/ns		<±100		ps	$V_{IN} = 0$ V to 5 V
Slew Rate: 5.0 V/ns		<±350		ps	$V_{IN} = 0$ V to 5 V
Amplitude: 1.0 V, 3.0 V, 5.0 V		<±200		ps	$V_{IN} = 1.0$ V/ns
Equivalent Input Rise Time		450		ps	$V_{IN} = 0$ V to 3 V, 3 V/ns
Pulse Width Linearity		<±200		ps	$V_{IN} = 0$ V to 3 V, 3 V/ns, PW = 3 ns to 8 ns
Settling Time		25		ns	Settling to ±8 mV, $V_{IN} = 1$ V to 0 V
Latch Timing					
Input Pulse Width		1.68		ns	
Setup Time		1.0		ns	
Hold Time		1.1		ns	
Hysteresis		6		mV	Latch inputs programmed for hysteresis

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ACTIVE LOAD SPECIFICATIONS

All specifications are at T_J = 85°C ± 5°C, V_{CC} = 11 V ± 3%, V_{EE} = −6 V = ±3%, unless otherwise noted. All temperature coefficients are measured at T_J = 75°C to 95°C.

Table 3.

Parameter	Min	Typ	Max	Unit	Test Conditions
INPUT CHARACTERISTICS					
INHL, $\overline{INHL}$					
Input Voltage	−2		+3	V	IOHC = 1 V, IOLC = 1 V, VCOM = 2 V, OUT_L = 0 V
Bias Current	−250		+250	µA	INHL, $\overline{INHL}$ = −2 V, +3 V
IOHC Current Program Range					
IOH = 0 mA to −40 mA	0		4	V	OUT_L = −0.7 V, +7 V
IOLC Current Program Range					
IOL = 0 mA to 40 mA	0		4	V	OUT_L = −2 V, +5.7 V
IOHC, IOLC Input Bias Current	−300		+300	µA	IOLC = 0 V, 4.0 V and IOHC = 0 V, 4.0 V
IOLRTN, IOHRTN Range	−2		+7	V	IOL = 40 mA, IOH = −40 mA, OUT_L = −2 V, +7 V
VDUT Range	−2		+7	V	IOL = 40 mA, IOH = −40 mA, OUT_L − VCOMI >1.3 V
VDUT Range, IOH = 0 mA to −40 mA	−0.7		+7	V	OUT_L − VCOM > 1.3 V
VDUT Range, IOL = 0 mA to 40 mA	−2		+5.7	V	VCOM − VDUT > 1.3 V
VCOMI Input Range	−2		+7	V	IOL = 40 mA, IOH = −40 mA
OUTPUT CHARACTERISTICS					
Accuracy					
Absolute Accuracy Error, Load Current	−0.3 − 100		+0.3 + 100	% I_{SET} + µA	IOL, IOH = 25 µA to 40 mA, VCOM = 0 V, OUT_L = ±2 V and IOL = 25 µA to 40 mA, VCOM = 7 V, OUT_L = 5.7 V and IOH = 25 µA to 40 mA, VCOM = −2 V, OUT_L = −0.7 V
VCOM Buffer					
Offset Error	−50		+50	mV	IOL, IOH = 40 mA, VCOMI = 0 V, OUT_L = VCOM
Bias Current	−10	+1	+10	µA	VCOMI = 0 V, OUT_L = VCOM
Gain Error	−0.2		+0.2	%	IOL, IOH = 40 mA, VCOMI = −1 V to +6 V, V_{OUT} = VCOM
Linearity Error	−10		+10	mV	IOL, IOH = 40 mA, VCOMI = −1 V to +6 V, V_{OUT} = VCOM
Output Current Temperature Coefficient		<±2		µA/°C	Measured at IOH, IOL = 200 µA
DYNAMIC PERFORMANCE					
Propagation Delay					
±I_{OUT} to Inhibit		1.9		ns	VCOM = ±2 V, IOL = 20 mA, IOH = −20 mA
Inhibit to ±I_{OUT}		2.8		ns	VCOM = ±2 V, IOL = 20 mA, IOH = 20 mA
Propagation Delay Matching		<1.8		ns	
Input/Output Spike		240		mV	VCOM = 0 V, IOL = 20 mA, IOH = −20 mA
Settling Time to 15 mV		<50		ns	IOL = 20 mA, IOH = −20 mA, 50 Ω load to ±15 mV
Settling Time to 4 mV		<10		µs	IOL = 20 mA, IOH = −20 mA, 50 Ω load to ±4 mV

TOTAL FUNCTION SPECIFICATIONS

All specifications are at $T_J = 85°C \pm 5°C$, $V_{CC} = 11\ V \pm 3\%$, $V_{EE} = -6\ V = \pm3\%$ unless otherwise noted. All temperature coefficients are measured at $T_J = 75°C$ to $95°C$.

Table 4.

Parameter[1]	Min	Typ	Max	Unit	Test Conditions
OUTPUT CHARACTERISTICS					
Output Leakage Current, $V_{OUT} = -1\ V$ to $+5\ V$	−250		+250	nA	
Output Leakage Current, $V_{OUT} = -2\ V$ to $+7\ V$	−500		+500	µA	
Output Capacitance		8		pF	Driver and load inhibited
POWER SUPPLIES					
Total Supply Range		17		V	
Positive Supply, V_{CC}		11		V	
Negative Supply, V_{EE}		−6		V	
Positive Supply Current			280	mA	Driver = I_{INH}, I_{LOAD} program = 40 mA, load = active
Negative Supply Current			290	mA	Driver = I_{INH}, I_{LOAD} program = 40 mA, load = active
VCCO Current		65		mA	VCCO = 3.3 V, comparator output 150 Ω to GND
Total Power Dissipation			4.8	W	Driver = I_{INH}, I_{LOAD} program = 40 mA, load = active
Temperature Sensor Gain Factor		1		µA/K	$R_{LOAD} = 10\ k\Omega$, $V_{SOURCE} = 11\ V$

[1] Connecting or shorting the decoupling pins to ground results in the destruction of the device.

Table 5. Driver Truth Table

DATA	$\overline{DATA}$	IOD	$\overline{IOD}$	RLD	$\overline{RLD}$	Output State
0	1	1	0	X	X	V_L
1	0	1	0	X	X	V_H
X	X	0	1	0	1	Inhibit
X	X	0	1	1	0	V_T

Table 6. Comparator Truth Table

	V_{OUT}	LEH	$\overline{LEH}$	LEL	$\overline{LEL}$	Output States			
						QH	$\overline{QH}$	QL	$\overline{QL}$
>HCOMP	>LCOMP	1	0	1	0	1	0	1	0
>HCOMP	<LCOMP	1	0	1	0	1	0	0	1
<HCOMP	>LCOMP	1	0	1	0	0	1	1	0
<HCOMP	<LCOMP	1	0	1	0	0	1	0	1
X	X	0	1	0	1	QH (t − 1)	$\overline{QH}$ (t − 1)	QL (t − 1)	$\overline{QL}$ (t − 1)

Table 7. Active Load Truth Table

			Output States (Including Diode Bridge)		
OUT_L	INHL	$\overline{INHL}$	IOH	IOL	I(OUT_L)
<VCOM	0	1	V(IOHC) × 10 mA	V(IOLC) × 10 mA	IOL
>VCOM	0	1	V(IOHC) × 10 mA	V(IOLC) × 10 mA	IOH
X	1	0	0	0	0

ABSOLUTE MAXIMUM RATINGS

Table 8.

Parameter	Rating
Power Supply Voltage	
V_{CC} to GND	13 V
V_{EE} to GND	−8 V
V_{CC} to V_{EE}	20 V
VCCO to GND	10 V
PWRGND, HQGND, HQGND2	±0.4 V
Inputs	
DATA, $\overline{DATA}$, IOD, $\overline{IOD}$, RLD, $\overline{RLD}$	−2 V to +5 V
DATA to $\overline{DATA}$, IOD to $\overline{IOD}$, RLD to $\overline{RLD}$	±3 V
LEL, $\overline{LEL}$, LEH, $\overline{LEH}$	−2 V to +5 V
LEL to $\overline{LEL}$, LEH to $\overline{LEH}$	±3 V
INHL, $\overline{INHL}$	−2 V to +5 V
INHL to $\overline{INHL}$	±3 V
V_H, V_L, V_T, VCOMI to GND	−3 V to +8 V
V_H to V_L	±10 V
$(V_H − V_T)$ and $(V_T − V_L)$	±10 V
IOHC	±6 V
IOLC	±6 V
HCOMP	−3 V to +8 V
LCOMP	−3 V to +8 V
HCOMP, LCOMP to V_{OUT}	±10 V
Outputs	
V_{OUT} Short-Circuit Duration	Indefinite[1]
V_{OUT} Inhibit Mode	−3 V to +8 V
VHDCPL	Do not connect except for capacitor to V_{CC}
VLDCPL	Do not connect except for capacitor to V_{EE}
QH, $\overline{QH}$, QL, $\overline{QL}$ Maximum I_{OUT}	
Continuous	50 mA
Surge	100 mA
THERM	0 V to 13 V
IOHRTN, IOLRTN	−3.5 V to +8.5 V
VCOMS Short-Circuit Duration	3 sec[1]
Environmental	
Operating Temperature (Junction)	175°C
Storage Temperature Range	−65°C to +150°C
Lead Temperature (Soldering, 10 sec)[2]	260°C

[1] Output short-circuit protection is guaranteed as long as proper heat sinking is employed to ensure compliance with the operating temperature limits.
[2] To ensure lead coplanarity (±0.002 inches) and solderability, handling with bare hands should be avoided and the device should be stored in environments at 24°C ± 5°C (75°F ± 10°F) with relative humidity not to exceed 65%.

Stresses above those listed under Absolute Maximum Ratings may cause permanent damage to the device. This is a stress rating only; functional operation of the device at these or any other conditions above those indicated in the operational section of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

Table 9. Package Thermal Resistance

Airflow (m/s)	$θ_{JA}$ (°C/W)
0	42.7
1	37.8
2	36.4

For liquid-cooled applications, $θ_{JC} = 3.0$°C/W.

ESD CAUTION

ESD (electrostatic discharge) sensitive device. Charged devices and circuit boards can discharge without detection. Although this product features patented or proprietary protection circuitry, damage may occur on devices subjected to high energy ESD. Therefore, proper ESD precautions should be taken to avoid performance degradation or loss of functionality.
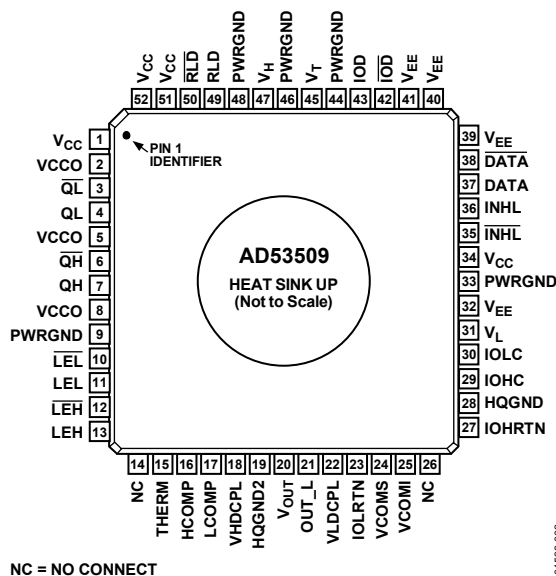
# PIN CONFIGURATION AND FUNCTION DESCRIPTIONS

Figure 2. Pin Configuration

Table 10. Pin Function Descriptions

Pin No.	Mnemonic	Description
1, 34, 51, 52	V_{CC}	Positive Power Supply.
2, 5, 8	VCCO	Comparator Output Power Supply.
3	$\overline{QL}$	Comparator Low Output, Inverting.
4	QL	Comparator Low Output, Noninverting.
6	$\overline{QH}$	Comparator High Output, Inverting.
7	QH	Comparator High Output, Noninverting.
9, 33, 44, 46, 48	PWRGND	Ground.
10	$\overline{LEL}$	Latch Enable Low Input, Inverting.
11	LEL	Latch Enable Low Input, Noninverting.
12	$\overline{LEH}$	Latch Enable High Input, Inverting.
13	LEH	Latch Enable High Input, Noninverting.
14, 26	NC	Do not connect.
15	THERM	Temperature Sensor Output.
16	HCOMP	High Comparator Threshold.
17	LCOMP	Low Comparator Threshold.
18	VHDCPL	Connect 39 nF compensation capacitor to V_{EE}.
19	HQGND2	Ground.
20	V_{OUT}	DUT Connection.
21	OUT_L	Active Load Output.
22	VLDCPL	Connect 39 nF compensation capacitor to V_{EE}.
23	IOLRTN	Active Load Low Inhibit Control.
24	VCOMS	VCOM Buffer Sense Output.
25	VCOMI	VCOM Input Voltage.
27	IOHRTN	Active Load High Inhibit Control.
28	HQGND	Ground.
29	IOHC	Active Load High Current Control Input.
30	IOLC	Active Load Low Current Control Input.

Pin No.	Mnemonic	Description
31	V_L	Low Driver Level.
32, 39, 40, 41	V_{EE}	Negative Power Supply.
35	$\overline{INHL}$	Inhibit Load Input, Inverting.
36	INHL	Inhibit Load Input, Noninverting.
37	DATA	Drive Data Input, Noninverting.
38	$\overline{DATA}$	Drive Data Input, Inverting.
42	$\overline{IOD}$	IO Data Input, Inverting.
43	IOD	IO Data Input, Noninverting.
45	V_T	Term Driver Level.
47	V_H	High Driver Level.
49	RLD	V_T/Inhibit Selection Input, Noninverting.
50	$\overline{RLD}$	V_T/Inhibit Selection Input, Inverting.

OUTLINE DIMENSIONS
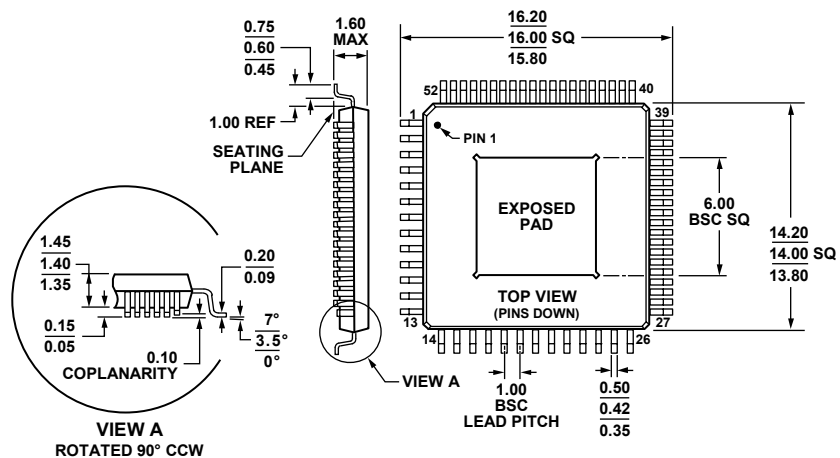
COMPLIANT TO JEDEC STANDARDS MS-026-BEA-HU

Figure 3. 52-Lead Low Profile Quad Flat Package, Exposed Pad [LQFP_EP]
(SW-52-1)
Dimensions shown in millimeters

ORDERING GUIDE

Model	Temperature Range	Package Description	Package Option	Ordering Quantity
AD53509JSW	0°C to 70°C	52-Lead LQFP_EP	SW-52-1	90
AD53509JSWZ[1]	0°C to 70°C	52-Lead LQFP_EP	SW-52-1	90

[1] Z = RoHS Compliant Part.

NOTES

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